











SNOS634C -MAY 1998-REVISED SEPTEMBER 2014

LM6181

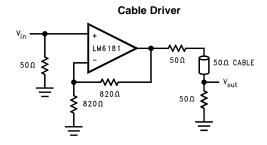
LM6181 100 mA, 100 MHz Current Feedback Amplifier

Features⁽¹⁾

- Slew Rate: 2000 V/µs
- Settling Time (0.1%): 50 ns
- Characterized for Supply Ranges: ± 5 V and ±15 V
- Low Differential Gain and Phase Error: 0.05%, 0.04°
- High Output Drive: $\pm 10 \text{ V}$ into 100Ω
- Ensured Bandwidth and Slew Rate
- Improved Performance Over EL2020, OP160, AD844, LT1223 and HA5004
- (1) Typical, unless otherwise noted

2 Applications

- Coax Cable Driver
- Video Amplifier
- Flash ADC Buffer
- High Frequency Filter
- Scanner and Imaging Systems



3 Description

The LM6181 current-feedback amplifier offers an unparalleled combination of bandwidth, slew-rate, and output current. The amplifier can directly drive up to 100 pF capacitive loads without oscillating and a 10-V signal into a 50- Ω or 75- Ω back-terminated coax cable system over the full industrial temperature range. This represents a radical enhancement in output drive capability for an 8-pin PDIP high-speed amplifier making it ideal for video applications.

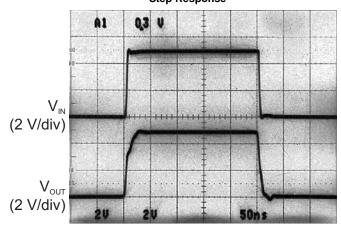
Built on TI's advanced high-speed VIP™ II (Vertically Integrated PNP) process, the LM6181 employs current-feedback providing bandwidth that does not vary dramatically with gain; 100 MHz at $A_V = -1$, 60 MHz at $A_V = -10$. With a slew rate of 2000V/ μ s, 2nd harmonic distortion of -50 dBc at 10 MHz and settling time of 50 ns (0.1%) the LM6181 dynamic performance makes it ideal for data acquisition, high speed ATE, and precision pulse amplifier applications.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
LM6181	PDIP (8)	9.81 mm × 6.35 mm		
LM6181	CDIP (8)	10.16 mm × 6.502 mm		
LM6181	SOIC (16)	9.90 mm × 3.91 mm		

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Step Response



Time (50 ns/div)



Table of Contents

1	Features 1	7 Typical Applications	22
2	Applications 1	7.1 Current Feedback Topology	
3 4	Description	7.2 Power Supply Bypassing and Layout Considerations	
5 6	Pin Configuration and Functions 3 Specifications 4 6.1 Absolute Maximum Ratings 4 6.2 Handling Ratings 4 6.3 Recommended Operating Conditions 4 6.4 Thermal Information 4 6.5 ±15V DC Electrical Characteristics 5 6.6 ±15V AC Electrical Characteristics 6	7.3 Feedback Resistor Selection: Rf	24 25 27 28 32
	6.7 ±5V DC Electrical Characteristics	9.2 Electrostatic Discharge Caution	32

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Revision B (May 2013) to Revision C	Page
•	Changed data sheet structure and organization. Added, updated, or renamed the following sections: Device Information Table, Pin Configuration and Functions, Application and Implementation; Device and Documentation Support; Mechanical, Packaging, and Ordering Information. Updated selected plots for readability	1
•	Changed "Junction Temperature Range" to " Operating Temperature Range" and deleted T _J	4
<u>•</u>	Deleted T _J = 25°C for Electrical Characteristics tables	5
CI	hanges from Revision A (May 2013) to Revision B	Page
•	Changed layout of National Data Sheet to TI format	1

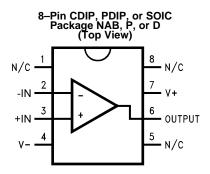
Submit Documentation Feedback

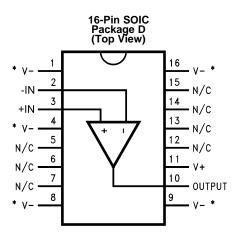
Copyright © 1998–2014, Texas Instruments Incorporated



5 Pin Configuration and Functions

* indicates heat sinking pins (1)





Pin Functions

	PIN							
NAME	NUMBER		I/O	DESCRIPTION				
NAME	NAB, P, D (8)	D (16)						
-IN	2	2	I	Inverting Input				
+IN	3	3	I	Non-inverting Input				
N/C	1, 5, 8	5, 6, 7 12, 13, 14, 15		No Connection				
OUTPUT	6	10	0	Output				
V-	4	1, 4, 8, 9, 16	I	Negative Supply				
V+	7	11	I	Positive Supply				

(1) The typical junction-to-ambient thermal resistance of the molded PDIP package soldered directly into a PC board is 102°C/W. The junction-to-ambient thermal resistance of the SOIC package mounted flush to the PC board is 70°C/W when pins 1, 4, 8, 9 and 16 are soldered to a total 2 in² 1 oz. copper trace. The 16-pin SOIC package must have pin 4 and at least one of pins 1, 8, 9, or 16 connected to V⁻ for proper operation. The typical junction-to-ambient thermal resistance of the SOIC package soldered directly into a PC board is 153°C/W.

Product Folder Links: LM6181



6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾⁽²⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
Supply Voltage				±18	V
Differential Input Voltage			±6	V	
Input Voltage				±Supply Voltage	V
Inverting Input Current				15	mA
	PDIP Package	Soldering (10 sec)		260	°C
Soldering Information	2010 5 1	Vapor Phase (60 seconds)		215	°C
	SOIC Package Infrared (15 seconds)			220	°C
Output Short Circuit			See ⁽³⁾		
Maximum Junction Tempe	erature			150	°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating ratings indicate conditions the device is intended to be functional, but device parameter specifications may not be ensured under these conditions. For ensured specifications and test conditions, see the Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications
- (3) Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of ±130 mA over a long term basis may adversely affect reliability.

6.2 Handling Ratings

			MIN	MAX	UNIT
T _{stg}	Storage temperature rang	e	-65	+150	°C
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)		±3000	V

JEDEC document JEP155 states that 3000-V HBM allows safe manufacturing with a standard ESD control process. Human body model 100 pF and 1.5 kΩ.

6.3 Recommended Operating Conditions(1)

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Supply Voltage Range		7	32	V
Operating Temperature Denge	LM6181AM	-55	+125	°C
Operating Temperature Range	LM6181AI, LM6181I	-40	+85	°C

⁽¹⁾ For ensured Military Temperature Range parameters see RETS6181X.

6.4 Thermal Information

	THERMAL METRIC ⁽¹⁾⁽²⁾	P (PDIP)	D (SOIC)	D (SOIC)	UNIT
		8 PINS	8 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	102	153	70	°C/W
R ₀ JC(top)	Junction-to-case (top) thermal resistance	42	42	38	C/VV

1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

Product Folder Links: LM6181

⁽²⁾ The typical junction-to-ambient thermal resistance of the molded PDIP package soldered directly into a PC board is 102°C/W. The junction-to-ambient thermal resistance of the SOIC package mounted flush to the PC board is 70°C/W when pins 1, 4, 8, 9 and 16 are soldered to a total 2 in 2 1 oz. copper trace. The 16-pin SOIC package must have pin 4 and at least one of pins 1, 8, 9, or 16 connected to V- for proper operation. The typical junction-to-ambient thermal resistance of the SOIC package soldered directly into a PC board is 153°C/W."



6.5 ±15V DC Electrical Characteristics

The following specifications apply for Supply Voltage = ± 15 V, R_F = 820 Ω , and R_L = 1 k Ω unless otherwise noted. **Boldface** limits apply at the temperature extremes.

	PARAMETER	TEST CONDITIONS	LM61	LM6181AM LM6181AI		181AI	LM6	1811	11507
			TYP ⁽¹⁾	LIMIT ⁽²⁾	TYP ⁽¹⁾	LIMIT ⁽²⁾	TYP ⁽¹⁾	LIMIT ⁽²⁾	UNIT
V _{OS}	Input Offset Voltage		2.0	3.0 4.0	2.0	3.0 3.5	3.5	5.0 5.5	mV max
TC V _{OS}	Input Offset Voltage Drift		5.0		5.0		5.0		μV/°C
I _B	Inverting Input Bias Current		2.0	5.0 12.0	2.0	5.0 12.0	5.0	10 17.0	μA
	Non-Inverting Input Bias Current		0.5	1.5 3.0	0.5	1.5 3.0	2.0	3.0 5.0	max
TC I _B	Inverting Input Bias Current Drift		30		30		30		- A /0C
	Non-Inverting Input Bias Current Drift		10		10		10		nA/°C
I _B PSR	Inverting Input Bias Current Power Supply Rejection	$V_S = \pm 4.5 V, \pm 16 V$	0.3	0.5 3.0	0.3	0.5 3.0	0.3	0.75 4.5	
	Non-Inverting Input Bias Current Power Supply Rejection	V _S = ±4.5V, ±16V	0.05	0.5 1.5	0.05	0.5 1.5	0.05	0.5 3.0	µA/V
I _B CMR	Inverting Input Bias Current Common Mode Rejection	-10V ≤ V _{CM} ≤ +10V	0.3	0.5 0.75	0.3	0.5 0.75	0.3	0.75 1.0	max
	Non-Inverting Input Bias Current Common Mode Rejection	-10V ≤ V _{CM} ≤ +10V	0.1	0.5 0.5	0.1	0.5 0.5	0.1	0.5 0.5	
CMRR	Common Mode Rejection Ratio	-10V ≤ V _{CM} ≤ +10V	60	50 50	60	50 50	60	50 50	dB min
PSRR	Power Supply Rejection Ratio	$V_S = \pm 4.5 V, \pm 16 V$	80	70 70	80	70 70	80	70 65	dB min
R _O	Output Resistance	$A_V = -1$, $f = 300 \text{ kHz}$	0.2		0.2		0.2		Ω
R _{IN}	Non-Inverting Input Resistance		10		10		10		MΩ min
Vo	Output Voltage Swing	$R_L = 1 k\Omega$	12	11 11	12	11 11	12	11 11	>
		R _L = 100Ω	11	10 7.5	11	10 8.0	11	10 8.0	min
I _{SC}	Output Short Circuit Current		130	100 75	130	100 85	130	100 85	mA min
Z _T	Transimpedance	$R_L = 1 k\Omega$	1.8	1.0 0.5	1.8	1.0 0.5	1.8	0.8 0.4	ΜΩ
		$R_L = 100\Omega$	1.4	0.8 0.4	1.4	0.8 0.4	1.4	0.7 0.35	min
Is	Supply Current	No Load, V _O = 0V	7.5	10 10	7.5	10 10	7.5	10 10	mA max
V_{CM}	Input Common Mode Voltage Range		V ⁺ - 1.7 V ⁻ + 1.7		V ⁺ - 1.7 V ⁻ + 1.7		V ⁺ - 1.7 V ⁻ + 1.7		٧

⁽¹⁾ Typical values represent the most likely parametric norm.

⁽²⁾ All limits ensured at room temperature (standard type face) or at operating temperature extremes (bold face type).



6.6 ±15V AC Electrical Characteristics

The following specifications apply for Supply Voltage = ± 15 V, R_F = 820 Ω , R_L = 1 k Ω unless otherwise noted. **Boldface** limits apply at the temperature extremes.

	PARAMETER	TEST CONDITIONS	LM61	81AM	LM61	81AI	LM61	81I	UNIT
			TYP ⁽¹⁾	LIMIT ⁽²⁾	TYP ⁽¹⁾	LIMIT ⁽²⁾	TYP ⁽¹⁾	LIMIT ⁽²⁾	
		A _V = +2	100		100		100		
BW	Closed Loop	A _V = +10	80		80		80		
BW	Bandwidth -3 dB	A _V = −1	100	80	100	80	100	80	MHz min
		A _V = −10	60		60		60		
PBW	Power Bandwidth	$A_V = -1, V_O = 5 V_{PP}$	60		60		60		
		Overdriven	2000		2000		2000		1//
SR	Slew Rate	$A_V = -1$, $V_O = \pm 10V$, $R_L = 150\Omega^{(3)}$	1400	1000	1400	1000	1400	1000	V/µs min
t _s	Settling Time (0.1%)	$A_V = -1, V_O = \pm 5V$ $R_L = 150\Omega$	50		50		50		
t _r , t _f	Rise and Fall Time	$V_O = 1 V_{PP}$	5		5		5		ns
t _p	Propagation Delay Time	$V_O = 1 V_{PP}$	6		6		6		
i _{n(+)}	Non-Inverting Input Noise Current Density	f = 1 kHz	3		3		3		pA/√Hz
i _{n(-)}	Inverting Input Noise Current Density	f = 1 kHz	16		16		16		pA/√Hz
e _n	Input Noise Voltage Density	f = 1 kHz	4		4		4		pA/√Hz
	Second Harmonic Distortion	2 V _{PP} , 10 MHz	-50		-50		-50		dD.a
	Third Harmonic Distortion	2 V _{PP} , 10 MHz	-55		-55		-50		dBc
	Differential Gain	$R_L = 150\Omega$, $A_V = +2$, NTSC	0.05%	-	0.05%		0.05%		
	Differential Phase	$R_L = 150\Omega$, $A_V = +2$, NTSC	0.04		0.04		0.04		Deg

Typical values represent the most likely parametric norm.

All limits ensured at room temperature (standard type face) or at operating temperature extremes (bold face type).

Measured from +25% to +75% of output waveform.



6.7 ±5V DC Electrical Characteristics

The following specifications apply for Supply Voltage = ± 5 V, R_F = 820 Ω , and R_L = 1 k Ω unless otherwise noted. **Boldface** limits apply at the temperature extremes.

	PARAMETER	TEST CONDITIONS	LM618	31AM	LM61			181I	LINUT
			TYP ⁽¹⁾	LIMIT ⁽²⁾	TYP ⁽¹⁾	LIMIT ⁽²⁾	TYP ⁽¹⁾	LIMIT ⁽²⁾	UNIT
V _{OS}	Input Offset Voltage		1.0	2.0 3.0	1.0	2.0 2.5	1.0	3.0 3.5	mV max
TC V _{OS}	Input Offset Voltage Drift		2.5		2.5		2.5		μV/°C
I _B	Inverting Input Bias Current		5.0	10 22	5.0	10 22	5.0	17.5 27.0	μA
	Non-Inverting Input Bias Current		0.25	1.5 1.5	0.25	1.5 1.5	0.25	3.0 5.0	max
TC I _B	Inverting Input Bias Current Drift		50		50		50		nA/°C
	Non-Inverting Input Bias Current Drift		3.0		3.0		3.0		na/ C
I _B PSR	Inverting Input Bias Current Power Supply Rejection	$V_S = \pm 4.0V, \pm 6.0V$	0.3	0.5 0.5	0.3	0.5 0.5	0.3	1.0 1.0	
	Non-Inverting Input Bias Current Power Supply Rejection	V _S = ±4.0V, ±6.0V	0.05	0.5 0.5	0.05	0.5 0.5	0.05	0.5 0.5	µA/V
I _B CMR	Inverting Input Bias Current Common Mode Rejection	$-2.5V \le V_{CM} \le +2.5V$	0.3	0.5 1.0	0.3	0.5 1.0	0.3	1.0 1.5	max
	Non-Inverting Input Bias Current Common Mode Rejection	$-2.5V \le V_{CM} \le +2.5V$	0.12	0.5 1.0	0.12	0.5 0.5	0.12	0.5 0.5	
CMRR	Common Mode Rejection Ratio	$-2.5V \le V_{CM} \le +2.5V$	57	50 47	57	50 47	57	50 47	dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 4.0V, \pm 6.0V$	80	70 70	80	70 70	80	64 64	min
R _O	Output Resistance	$A_V = -1$, $f = 300 \text{ kHz}$	0.25		0.25		0.25		Ω
R _{IN}	Non-Inverting Input Resistance		8		8		8		MΩ min
V _O	Output Voltage Swing	$R_L = 1 k\Omega$	2.6	2.25 2.2	2.6	2.25 2.25	2.6	2.25 2.25	V
		$R_L = 100\Omega$	2.2	2.0 2.0	2.2	2.0 2.0	2.2	2.0 2.0	min
I _{SC}	Output Short Circuit Current		100	75 70	100	75 70	100	75 70	mA min
Z_{T}	Transimpedance	$R_L = 1 k\Omega$	1.4	0.75 0.35	1.4	0.75 0.4	1.0	0.6 0.3	-
		$R_L = 100\Omega$	1.0	0.5 0.25	1.0	0.5 0.25	1.0	0.4 0.2	min
I _S	Supply Current	No Load, V _O = 0V	6.5	8.5 8.5	6.5	8.5 8.5	6.5	8.5 8.5	mA max
V_{CM}	Input Common Mode Voltage Range		V ⁺ - 1.7 V ⁻ + 1.7		V ⁺ - 1.7 V ⁻ + 1.7		V ⁺ - 1.7 V ⁻ + 1.7		V

⁽¹⁾ Typical values represent the most likely parametric norm.

⁽²⁾ All limits ensured at room temperature (standard type face) or at operating temperature extremes (bold face type).



6.8 ±5V AC Electrical Characteristics

The following specifications apply for Supply Voltage = ± 5 V, R_F = 820 Ω , and R_L = 1 k Ω unless otherwise noted. **Boldface** limits apply at the temperature extremes.

	PARAMETER	TEST CONDITIONS	LM61	81AM	LM61	81AI	LMe	6181I	
			TYP ⁽¹⁾	LIMIT ⁽²⁾	TYP ⁽¹⁾	LIMIT ⁽²⁾	TYP ⁽¹⁾	LIMIT ⁽²⁾	UNIT
BW	Closed Loop	A _V = +2	50		50		50		
	Bandwidth −3 dB	A _V = +10	40		40		40		
		A _V = −1	55	35	55	35	55	35	MHz min
		A _V = −10	35		35		35		
PBW	Power Bandwidth	$A_V = -1$, $V_O = 4 V_{PP}$	40		40		40		
SR	Slew Rate	$A_V = -1$, $V_O = \pm 2V$, $R_L = 150\Omega^{(3)}$	500	375	500	375	500	375	V/µs min
t _s	Settling Time (0.1%)	$A_V = -1$, $V_O = \pm 2V$ $R_L = 150\Omega$	50		50		50		
t _r , t _f	Rise and Fall Time	$V_O = 1 V_{PP}$	8.5		8.5		8.5		ns
t _p	Propagation Delay Time	$V_O = 1 V_{PP}$	8		8		8		
i _{n(+)}	Non-Inverting Input Noise Current Density	f = 1 kHz	3		3		3		pA/√Hz
i _{n(-)}	Inverting Input Noise Current Density	f = 1 kHz	16		16		16		pA/√Hz
e _n	Input Noise Voltage Density	f = 1 kHz	4		4		4		pA/√Hz
	Second Harmonic Distortion	2 V _{PP} , 10 MHz	-45		-45		-45		alD a
	Third Harmonic Distortion	2 V _{PP} , 10 MHz	-55		-55		-55		dBc
	Differential Gain	$R_L = 150 \Omega, A_V = +2,$ NTSC	0.063%		0.063%		0.063%		
	Differential Phase	$R_L = 150 \Omega$, $A_V = +2$, NTSC	0.16		0.16		0.16		Deg

Typical values represent the most likely parametric norm.

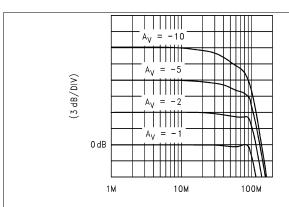
All limits ensured at room temperature (standard type face) or at operating temperature extremes (bold face type).

Measured from +25% to +75% of output waveform.



6.9 Typical Performance Characteristics

 $T_A = 25$ °C unless otherwise noted



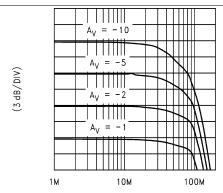
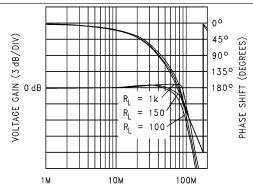


Figure 1. Closed-loop Frequency Response V_S = ±15V; R_f = 820 Ω ; R_L = 1 $k\Omega$

Figure 2. Closed-loop Frequency Response $V_S = \pm 15V$; $R_f = 820~\Omega$; $R_L = 150\Omega$



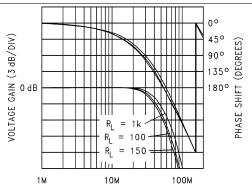
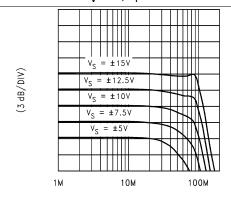


Figure 3. Unity Gain Frequency Response $V_S = \pm 15V$; $A_V = +1$; $R_f = 820 \Omega$

Figure 4. Unit Gain Frequency Response V_S = ± 5 V; A_V = ± 1 ; R_f = 820 Ω



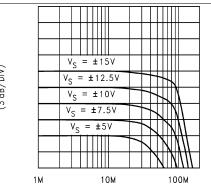


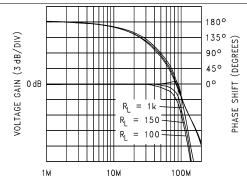
Figure 5. Frequency Response Vs Supply Voltage $A_V = -1$; $R_f = 820 \ \Omega$; $R_L = 1 \ k\Omega$

Figure 6. Frequency Response vs. Supply Voltage $A_V = -1$; $R_f = 820 \ \Omega; \ R_L = 150 \ \Omega$

TEXAS INSTRUMENTS

Typical Performance Characteristics (continued)

 $T_A = 25$ °C unless otherwise noted



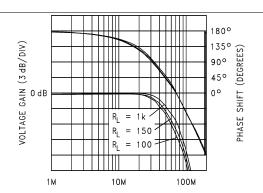
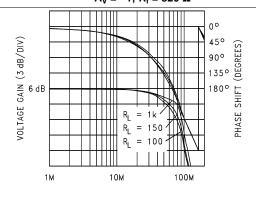


Figure 7. Inverting Gain Frequency Response V_S = ± 15 V; A_V = -1; R_f = 820 Ω

Figure 8. Inverting Gain Frequency Response V_S = ± 5 V; $A_V = -1; R_f = 82 \ 0\Omega$



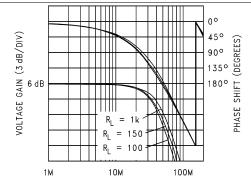
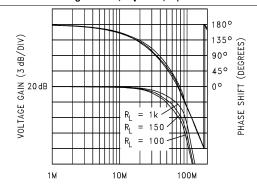


Figure 9. Non-inverting Gain Frequency Response $V_S = \pm 15 V; \ A_V = \pm 2; \ R_f = 820 \ \Omega$

Figure 10. Non-inverting Gain Frequency Response $V_S=\pm 5V;~A_V=+2;~R_f=820~\Omega$



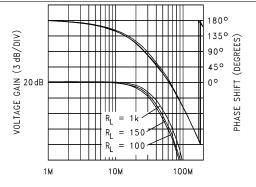
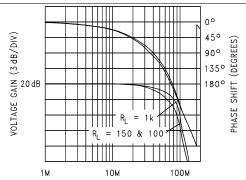


Figure 11. Inverting Gain Frequency Response $V_S = \pm 15V; A_V = -10; R_f = 820 \Omega$

Figure 12. Inverting Gain Frequency Response $V_S=\pm 5V;\, A_V=-10;\, R_f=820\,\, \Omega$



 $T_A = 25$ °C unless otherwise noted



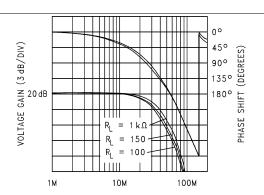
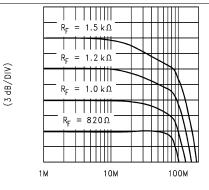


Figure 13. Non-inverting Gain Frequency Response $V_S=\pm 15V;\ A_V=\pm 10;\ R_f=820\ \Omega$

Figure 14. Non-inverting Gain Frequency Response $V_S=\pm5V;\ A_V=\pm10;\ R_f=820\ \Omega$



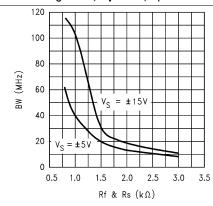
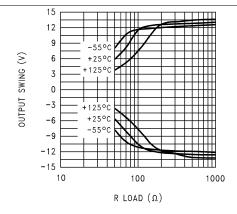


Figure 15. Non-inverting Gain Frequency Compensation $V_S=\pm 15V;\, A_V=+2;\, R_L=150\,\, \Omega$

Figure 16. Bandwidth vs R_f & R_S $A_V = -1$, $R_L = 1$ $k\Omega$



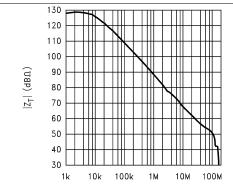


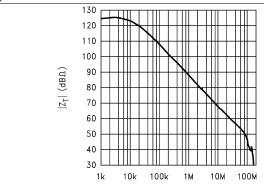
Figure 17. Output Swing vs R_{LOAD} Pulsed, $V_S = \pm 15V$, $I_{IN} = \pm 200~\mu A$, $V_{IN+} = 0V$

Figure 18. Transimpedance vs Frequency $V_S = \pm 15V R_L = 1 k\Omega$

TEXAS INSTRUMENTS

Typical Performance Characteristics (continued)

 $T_A = 25$ °C unless otherwise noted



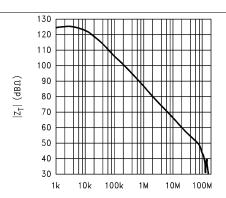
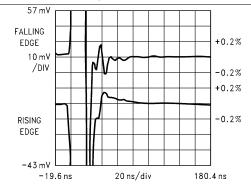


Figure 19. Transimpedance vs Frequency $V_S = \pm 15V R_L = 100\Omega$





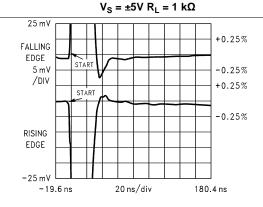
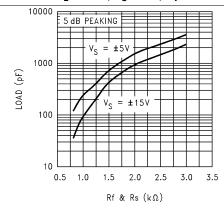


Figure 21. Settling Response $V_S = \pm 15V$; $R_L = 150\Omega$; $V_O = \pm 5V$; $A_V = -1$

Figure 22. Settling Response $V_S = \pm 5V$; $R_L = 150 \ \Omega$; $V_O = \pm 2V$; $A_V = -1$



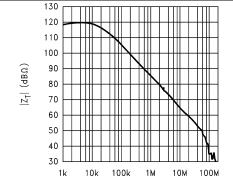
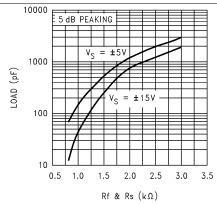


Figure 23. Suggested R_f and R_S for C_L $A_V = -1$; $R_L = 150\Omega$

Figure 24. Transimpedance vs Frequency $V_S = \pm 5V R_L = 100\Omega$



T_A = 25°C unless otherwise noted



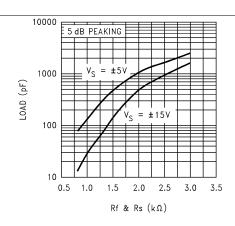
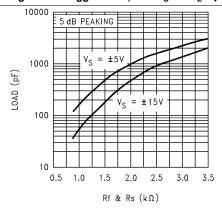


Figure 25. Suggested R_f and R_S for C_L $A_V = -1$





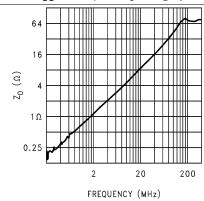
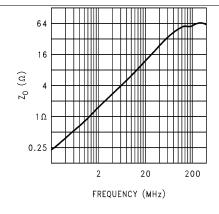


Figure 27. Suggested R_f and R_S for C_L A_V = +2

Figure 28. Output Impedance vs Freq $V_S = \pm 15V$; $A_V = -1$ $R_f = 820$ Ω



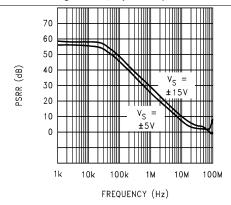


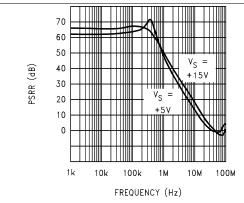
Figure 29. Output Impedance vs Freq $V_S = \pm 5V$; $A_V = -1$ $R_f = 820$ Ω

Figure 30. PSRR (V_S^+) vs Frequency

TEXAS INSTRUMENTS

Typical Performance Characteristics (continued)

 $T_A = 25$ °C unless otherwise noted



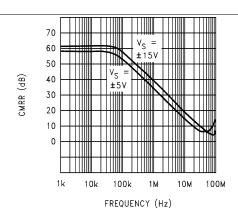


Figure 31. PSRR (V_S⁻) vs Frequency

100

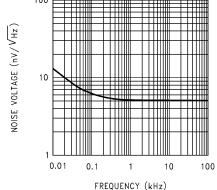


Figure 32. CMRR vs Frequency

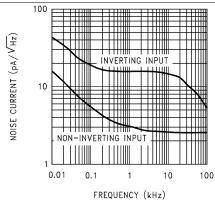


Figure 33. Input Voltage Noise vs Frequency

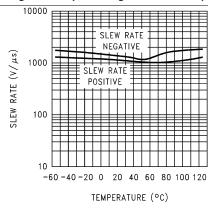


Figure 34. Input Current Noise vs Frequency

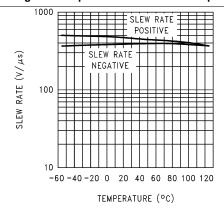
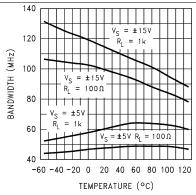


Figure 35. Slew Rate vs Temperature $A_V = -1$; $R_L = 150 \ \Omega, \ V_S = \pm 15V$

Figure 36. Slew Rate vs Temperature A_V = -1; $R_L = 150~\Omega,~V_S = \pm 5V$



 $T_A = 25$ °C unless otherwise noted



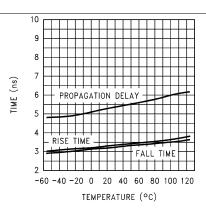
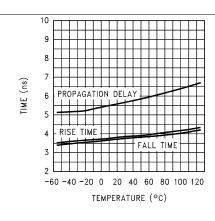


Figure 37. -3 dB Bandwidth vs Temperature $A_V = -1$

Figure 38. Small Signal Pulse response vs Temp, $A_V = +1 \ V_S = \pm 15 V; \ R_L = 1 \ k\Omega$



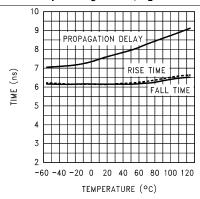
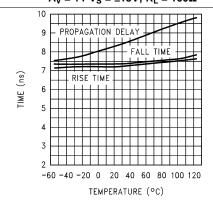


Figure 39. Small Signal Pulse Response vs Temp, $A_V = +1 \ V_S = \pm 15 V; \ R_L = 100 \Omega$

Figure 40. Small Signal Pulse Response vs Temp, $A_V = +1 \ V_S = \pm 5 V; \ R_L = 1 \ k \Omega$



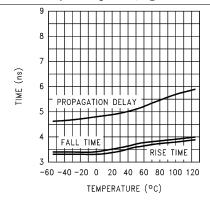


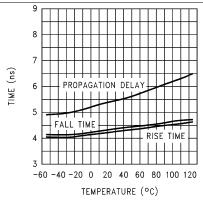
Figure 41. Small Signal Pulse Response vs Temp, $A_V = +1 \ V_S = \pm 5 V; \ R_L = 100 \Omega$

Figure 42. Small Signal Pulse Response vs Temp, $A_V = -1 \ V_S = \pm 15 V; \ R_L = 1 \ k\Omega$

TEXAS INSTRUMENTS

Typical Performance Characteristics (continued)

 $T_A = 25$ °C unless otherwise noted



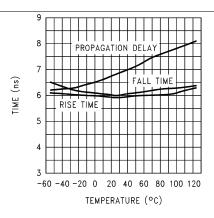
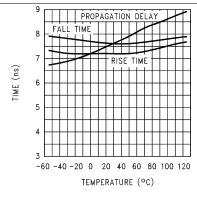


Figure 43. Small Signal Pulse Response vs Temp, $A_V = -1 \ V_S = \pm 15 V; \ R_L = 100 \Omega$

Figure 44. Small Signal Pulse Response vs Temp, $A_V = -1 \ V_S = \pm 5 V; \ R_L = 1 \ k \Omega$



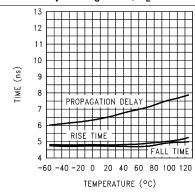


Figure 45. Small Signal Pulse Response vs Temp, $A_V = -1 \ V_S = \pm 5V; \ R_L = 100 \ \Omega$

13
12
11
10
9
9
PROPAGATION DELAY
7
6
7
6
FALL TIME
4
-60 -40 -20 0 20 40 60 80 100 120
TEMPERATURE (°C)

Figure 46. Small Signal Pulse Response vs Temp, $A_V = +2 \ V_S = \pm 15 V; \ R_L = 1 \ k\Omega$

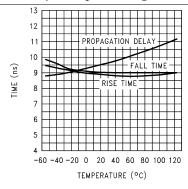


Figure 47. Small Signal Pulse Response vs Temp, $A_V = +2~V_S = \pm 15 V;~R_L = 100~\Omega$

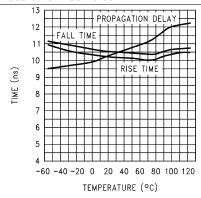
Figure 48. Small Signal Pulse Response vs Temp, $A_V = +2~V_S = \pm 5 V;~R_L = 1~k\Omega$

Submit Documentation Feedback

Copyright © 1998–2014, Texas Instruments Incorporated



 $T_A = 25$ °C unless otherwise noted



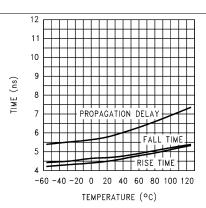
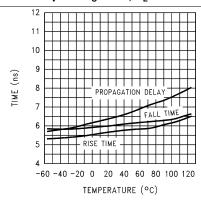


Figure 49. Small Signal Pulse Response vs Temp, $A_V = +2 \ V_S = \pm 5 V; \ R_L = 100 \ \Omega$

Figure 50. Small Signal Pulse Response vs Temp, $A_V = -10 \ V_S = \pm 15 V; \ R_L = 1 \ k\Omega$



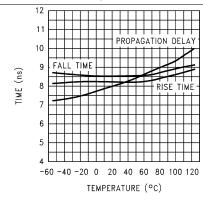
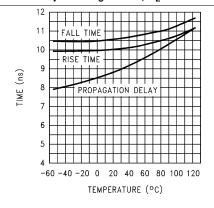


Figure 51. Small Signal Pulse Response vs Temp, $A_V = -10 \ V_S = \pm 15 V; \ R_L = 100 \Omega$

Figure 52. Small Signal Pulse Response vs Temp, $A_V = -10 \ V_S = \pm 5 V; \ R_L = 1 \ k\Omega$



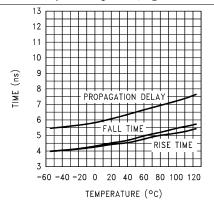


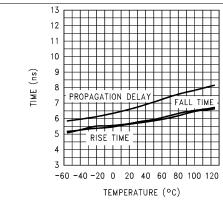
Figure 53. Small Signal Pulse Response vs Temp, $A_V = -10~V_S = \pm 5V;~R_L = 100\Omega$

Figure 54. Small Signal Pulse Response Vs Temp, $A_V = \pm 10 \ V_S = \pm 15 V; \ R_L = 1 \ k\Omega$

TEXAS INSTRUMENTS

Typical Performance Characteristics (continued)

 $T_A = 25$ °C unless otherwise noted



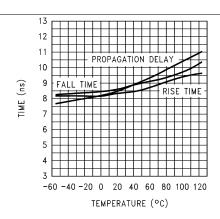
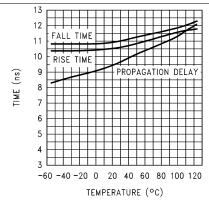


Figure 55. Small Signal Pulse Response vs Temp, $A_V = \pm 10 \ V_S = \pm 15 V; \ R_L = 100 \Omega$

Figure 56. Small Signal Pulse Response vs Temp, $A_V = +10 \ V_S = \pm 5 V; \ R_L = 1 \ k\Omega$



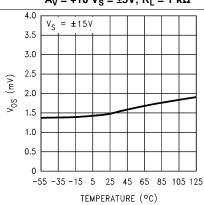
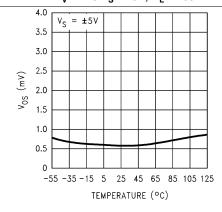


Figure 57. Small Signal Pulse Response vs Temp, $A_V = +10 \ V_S = \pm 5 V; \ R_L = 100 \Omega$

Figure 58. Offset Voltage vs temperature



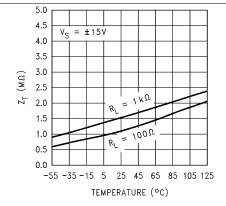
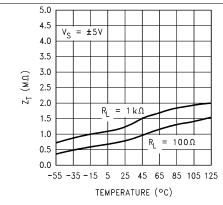


Figure 59. Offset Voltage vs Temperature

Figure 60. Transimpedance vs Temperature



 $T_A = 25$ °C unless otherwise noted



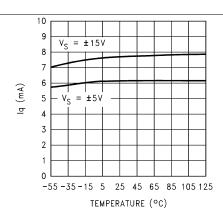


Figure 61. Transimpedance vs Temperature

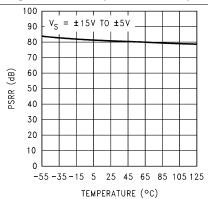


Figure 62. Quiescent Current vs Temperature

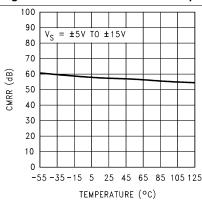


Figure 63. PSRR vs Temperature

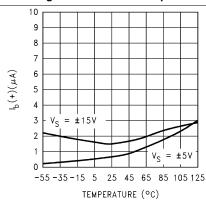


Figure 64. CMRR vs Temperature

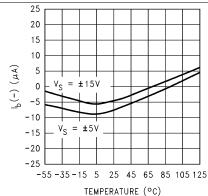
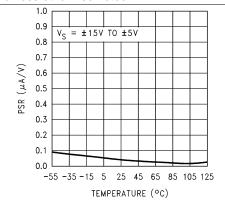


Figure 65. Non-inverting Bias Current vs Temperature

Figure 66. Inverting Bias Current vs Temperature



 $T_A = 25$ °C unless otherwise noted



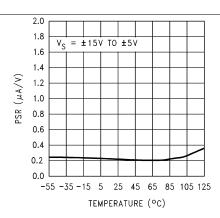


Figure 67. PSR $I_{B(+)}$ vs Temperature

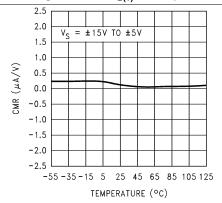


Figure 68. PSR $I_{B(-)}$ vs Temperature

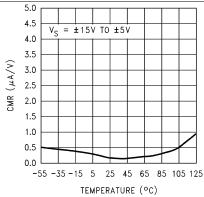


Figure 69. CMR $I_{B(+)}$ vs Temperature

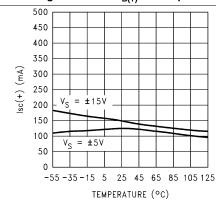


Figure 70. CMR $I_{B(-)}$ vs Temperature

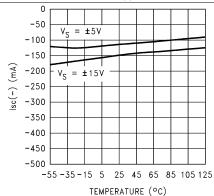
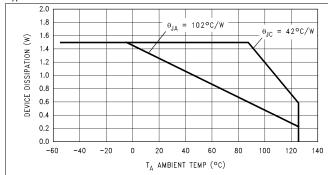


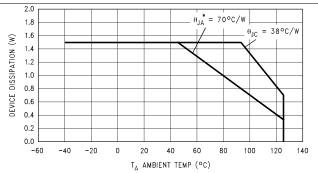
Figure 71. $I_{SC(+)}$ vs Temperature

Figure 72. $I_{SC(-)}$ vs Temperature



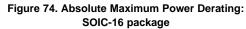
 $T_A = 25$ °C unless otherwise noted





 $^*\theta_{JA}$ = Thermal Resistance with 2 square inches of 1 ounce Copper tied to Pins 1, 8, 9 and 16.

Figure 73. Absolute Maximum Power Derating: PDIP Package



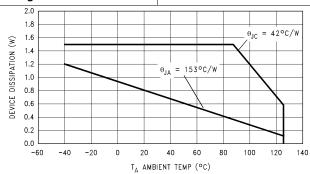


Figure 75. Absolute Maximum Power Derating: SOIC-8 package

Copyright © 1998–2014, Texas Instruments Incorporated



7 Typical Applications

7.1 Current Feedback Topology

For a conventional voltage feedback amplifier the resulting small-signal bandwidth is inversely proportional to the desired gain to a first order approximation based on the gain-bandwidth concept. In contrast, the current feedback amplifier topology, such as the LM6181, transcends this limitation to offer a signal bandwidth that is relatively independent of the closed-loop gain. Figure 76 and Figure 77 illustrate that for closed loop gains of -1 and -5 the resulting pulse fidelity suggests quite similar bandwidths for both configurations.

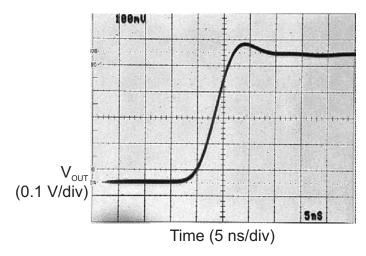
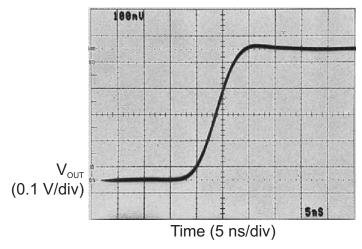


Figure 76. Step Response, Av = -1V/V



Variation of Closed Loop Gain from −1 to −5 Yields Similar Responses

Figure 77. Step Response, Av = -5V/V

22



Current Feedback Topology (continued)

The closed-loop bandwidth of the LM6181 depends on the feedback resistance, R_f. Therefore, R_S and not R_f, must be varied to adjust for the desired closed-loop gain as in Figure 78.

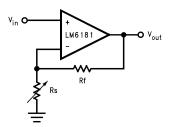


Figure 78. R_S Is Adjusted to Obtain the Desired Closed Loop Gain, A_{VCL}

7.2 Power Supply Bypassing and Layout Considerations

A fundamental requirement for high-speed amplifier design is adequate bypassing of the power supply. It is critical to maintain a wideband low-impedance to ground at the amplifiers supply pins to insure the fidelity of high speed amplifier transient signals. 10 μ F tantalum and 0.1 μ F ceramic bypass capacitors are recommended for each supply pin. The bypass capacitors should be placed as close to the amplifier pins as possible (0.5" or less).

7.3 Feedback Resistor Selection: R_f

Selecting the feedback resistor, R_f , is a dominant factor in compensating the LM6181. For general applications the LM6181 will maintain specified performance with an 820Ω feedback resistor. Although this value will provide good results for most applications, it may be advantageous to adjust this value slightly. Consider, for instance, the effect on pulse responses with two different configurations where both the closed-loop gains are 2 and the feedback resistors are 820Ω and 1640Ω , respectively. Figure 79 and Figure 80 illustrate the effect of increasing R_f while maintaining the same closed-loop gain—the amplifier bandwidth decreases. Accordingly, larger feedback resistors can be used to slow down the LM6181 (see -3 dB bandwidth vs R_f typical curves) and reduce overshoot in the time domain response. Conversely, smaller feedback resistance values than 820Ω can be used to compensate for the reduction of bandwidth at high closed loop gains, due to 2nd order effects. For example Figure 81 illustrates reducing R_f to 500Ω to establish the desired small signal response in an amplifier configured for a closed loop gain of 25.

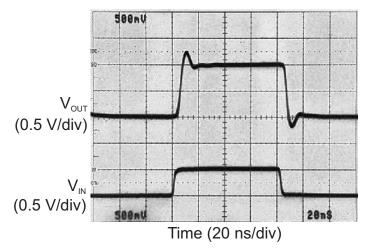
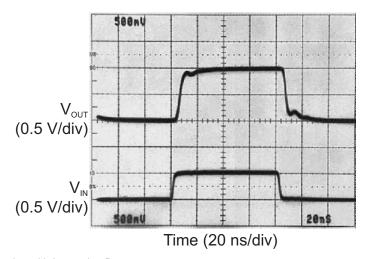


Figure 79. Step Response with Rf = 820 Ω

ISTRUMENTS

Feedback Resistor Selection: R_f (continued)



Increasing Compensation with Increasing R_f

Figure 80. Step Response with Rf = 1640 Ω

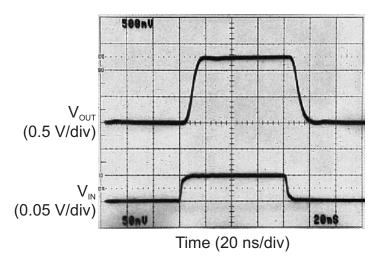


Figure 81. Reducing R_f for Large Closed Loop Gains, $R_f = 500 \Omega$

7.4 Slew Rate Considerations

The slew rate characteristics of current feedback amplifiers are different than traditional voltage feedback amplifiers. In voltage feedback amplifiers slew rate limiting or non-linear amplifier behavior is dominated by the finite availability of the 1st stage tail current charging the compensation capacitor. The slew rate of current feedback amplifiers, in contrast, is not constant. Transient current at the inverting input determines slew rate for both inverting and non-inverting gains. The non-inverting configuration slew rate is also determined by input stage limitations. Accordingly, variations of slew rates occur for different circuit topologies.



7.5 Driving Capacitive Loads

The LM6181 can drive significantly larger capacitive loads than many current feedback amplifiers. Although the LM6181 can directly drive as much as 100 pF without oscillating, the resulting response will be a function of the feedback resistor value. Figure 83 illustrates the small-signal pulse response of the LM6181 while driving a 50 pF load. Ringing persists for approximately 70 ns. To achieve pulse responses with less ringing either the feedback resistor can be increased (see Figure 23, Figure 25, and Figure 26), or resistive isolation can be used (10 Ω –51 Ω typically works well). Either technique, however, results in lowering the system bandwidth.

Figure 85 illustrates the improvement obtained with using a 47Ω isolation resistor.

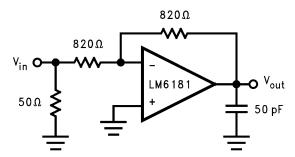


Figure 82. Cap Load Direct Drive

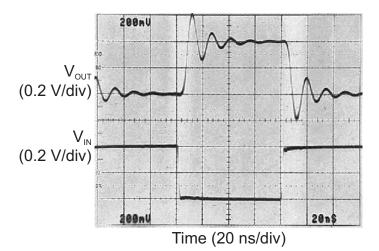


Figure 83. A_V = −1, LM6181 Can Directly Drive 50 pF of Load Capacitance with 70 ns of Ringing Resulting in Pulse Response



Driving Capacitive Loads (continued)

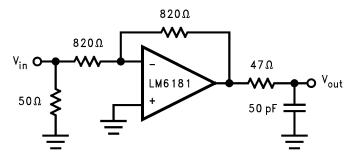
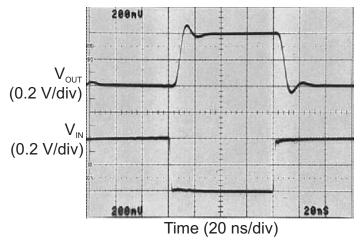


Figure 84. Cap Load Drive with Isolation Resistor



 R_f and R_S Could Be Increased to Maintain $A_V = -1$ and Improve Pulse Response Characteristics.

Figure 85. Resistive Isolation of C_L Provides Higher Fidelity Pulse Response



7.6 Capacitive Feedback

For voltage feedback amplifiers it is quite common to place a small lead compensation capacitor in parallel with feedback resistance, R_f. This compensation serves to reduce the amplifier's peaking in the frequency domain which equivalently tames the transient response. To limit the bandwidth of current feedback amplifiers, do not use a capacitor across R_f. The dynamic impedance of capacitors in the feedback loop reduces the amplifier's stability. Instead, reduced peaking in the frequency response, and bandwidth limiting can be accomplished by adding an RC circuit, as illustrated in Figure 87.

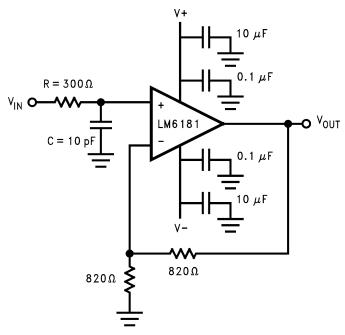


Figure 86. Using RC on Input to Affect Frequency Response

$$f - 3 dB = \frac{1}{2\pi RC} \tag{1}$$

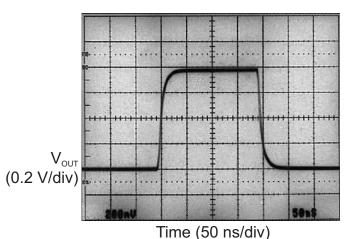


Figure 87. RC Limits Amplifier Bandwidth to 50 MHz, Eliminating **Peaking in the Resulting Pulse Response**



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Typical Application

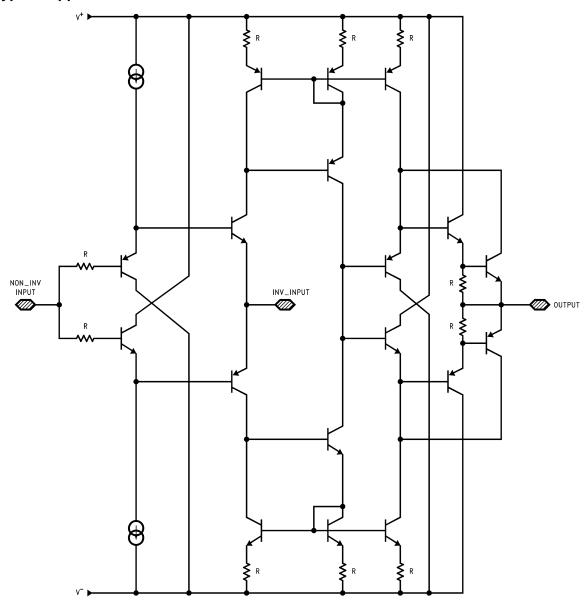


Figure 88. LM6181 Simplified Schematic



Typical Application (continued)

8.1.1 Typical Performance Characteristics

8.1.1.1 Overdrive Recovery

When the output or input voltage range of a high speed amplifier is exceeded, the amplifier must recover from an overdrive condition. The typical recovery times for open-loop, closed-loop, and input common-mode voltage range overdrive conditions are illustrated in Figure 90, Figure 92, and Figure 93, respectively.

The open-loop circuit of Figure 89 generates an overdrive response by allowing the ±0.5V input to exceed the linear input range of the amplifier. Typical positive and negative overdrive recovery times shown in Figure 90 are 5 ns and 25 ns, respectively.

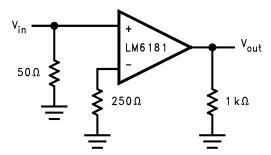


Figure 89. Open Loop Input Overdrive Test Circuit

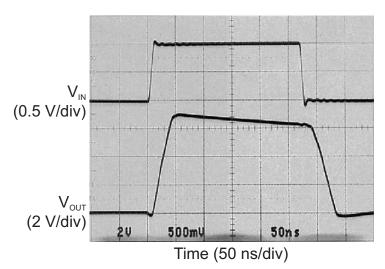


Figure 90. Open-Loop Overdrive Recovery Time of 5 ns, and 25 ns from Test Circuit in Figure 89



Typical Application (continued)

The large closed-loop gain configuration in Figure 91 forces the amplifier output into overdrive. Figure 92 displays the typical 30 ns recovery time to a linear output value.

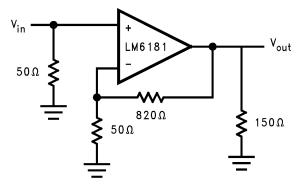


Figure 91. Overdrive Recovery Circuit under Large Closed Loop Gain Condition

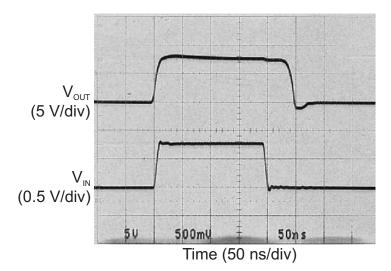


Figure 92. Closed-Loop Overdrive Recovery Time of 30 ns from Exceeding Output Voltage Range from Circuit in Figure 91



Typical Application (continued)

The common-mode input of the circuit in Figure 91 is exceeded by a 5V pulse resulting in a typical recovery time of 310 ns shown in Figure 93. The LM6181 supply voltage is ±5V.

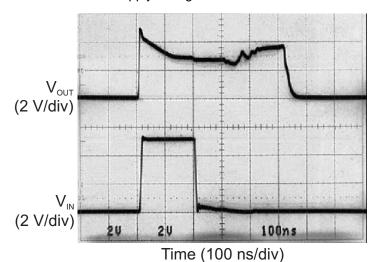


Figure 93. Exceptional Output Recovery from an Input that Exceeds the Common-Mode Range

Copyright © 1998–2014, Texas Instruments Incorporated



9 Device and Documentation Support

9.1 Trademarks

VIP is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

9.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

9.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: *LM6181*



PACKAGE OPTION ADDENDUM

27-Oct-2016

PACKAGING INFORMATION

www.ti.com

Orderable Device	Status	Package Type	_	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
LM6181IM-8/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LM618 1IM8	Samples
LM6181IMX-8/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LM618 1IM8	Samples
LM6181IN/NOPB	ACTIVE	PDIP	Р	8	40	Green (RoHS & no Sb/Br)	CU SN	Level-1-NA-UNLIM	-40 to 85	LM6181IN	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and



PACKAGE OPTION ADDENDUM

27-Oct-2016

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 11-Sep-2014

TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM6181IMX-8/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

www.ti.com 11-Sep-2014



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
LM6181IMX-8/NOPB	SOIC	D	8	2500	367.0	367.0	35.0	

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive **Amplifiers** amplifier.ti.com Communications and Telecom www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps DSP dsp.ti.com **Energy and Lighting** www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical Logic Security www.ti.com/security logic.ti.com

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com

Wireless Connectivity www.ti.com/wirelessconnectivity